

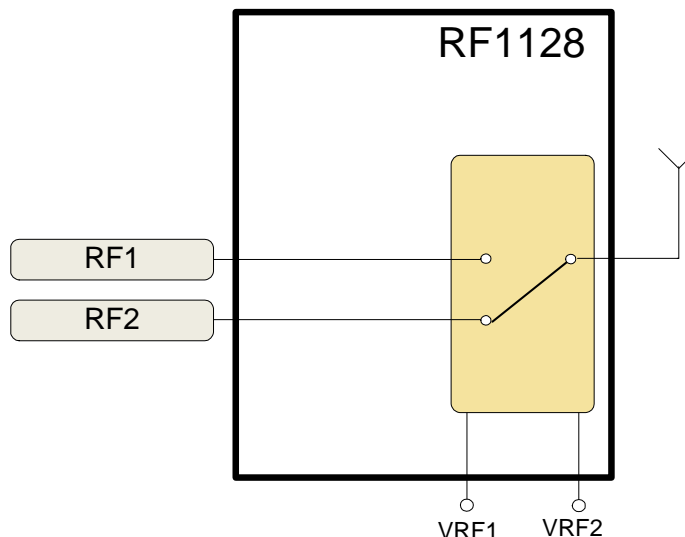


Features

- Broadband Performance: Low Frequency to 3.5GHz
- Very Low Insertion Loss:
 - 0.35dB at 1GHz
 - 0.40dB at 2GHz
- Excellent Linearity:
 - IIP2 > 108dBm (Typ.)
 - IIP3 > 67dBm (Typ.)
- PO.1dB: 32dBm (Typ.)
- Compact Footprint (2.0mmx1.3mmx0.35mm, 6-pin QFN)

Applications

- Cellular Handset Applications
- Antenna Tuning Applications
- Multi-mode GSM, W-CDMA Applications
- WLAN Applications



Functional Block Diagram

Product Description

The RF1128 is a single-pole double-throw (SPDT) switch designed for general purpose switching applications which require very low insertion loss and high power handling capability. The RF1128 is ideally suited for battery operated applications requiring high performance switching with very low DC power consumption. The RF1128 features very low insertion loss, broadband isolation and excellent linearity performance, and is operable from 1.8V to 3.3V control voltage. It is fabricated with 0.5μm GaAs pHEMT process, and is packaged in a very compact 2mmx1.3mm, 6-pin, leadless QFN package.

Ordering Information

| | |
|----------------|---|
| RF1128 | Broadband Medium Power (High Isolation) SPDT Switch |
| RF1128PCBA-410 | Fully Assembled Evaluation Board |

Optimum Technology Matching® Applied

- | | | | |
|--------------------------------------|--------------------------------------|--|-----------------------------------|
| <input type="checkbox"/> GaAs HBT | <input type="checkbox"/> SiGe BiCMOS | <input checked="" type="checkbox"/> GaAs pHEMT | <input type="checkbox"/> GaN HEMT |
| <input type="checkbox"/> GaAs MESFET | <input type="checkbox"/> Si BiCMOS | <input type="checkbox"/> Si CMOS | <input type="checkbox"/> RF MEMS |
| <input type="checkbox"/> InGaP HBT | <input type="checkbox"/> SiGe HBT | <input type="checkbox"/> Si BJT | <input type="checkbox"/> LDMOS |

Absolute Maximum Ratings

| Parameter | Rating | Unit |
|---|-------------|------|
| Voltage | 6.0 | V |
| Maximum Input Power (0.6GHz to 3.5GHz), RF1, RF2, 50Ω | +34 | dBm |
| Operating Temperature | -30 to +85 | °C |
| Storage Temperature | -65 to +100 | °C |



Caution! ESD sensitive device.

Exceeding any one or a combination of the Absolute Maximum Rating conditions may cause permanent damage to the device. Extended application of Absolute Maximum Rating conditions to the device may reduce device reliability. Specified typical performance or functional operation of the device under Absolute Maximum Rating conditions is not implied.

RoHS status based on EUDirective2002/95/EC (at time of this document revision).

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| Parameter | Specification | | | Unit | Condition |
|----------------------------|---------------|------|-------|------|---|
| | Min. | Typ. | Max. | | |
| | | | | | VRF1, VRF2=High=3V, VRF1=VRF2=Low=0V, Temp=25 °C |
| Operating Frequency | 600 | | 3500 | MHz | |
| Insertion Loss | | | | | |
| RFC - RF1, RFC - RF2 | | 0.25 | 0.35 | dB | RF ON, 50MHz to 600MHz |
| | | 0.35 | 0.50 | dB | RF ON, 824MHz to 960MHz |
| | | 0.40 | 0.55 | dB | RF ON, 1850MHz to 1990MHz |
| | | 0.45 | 0.60 | dB | RF ON, 2170MHz to 2500MHz |
| | | 0.55 | 0.70 | dB | RF ON, 3500MHz |
| RF Isolation | | | | | |
| RF1 - RF2 and RF2 - RF1 | 27 | 29 | | dB | RF ON, 600MHz |
| | 25 | 27 | | dB | RF ON, 824MHz to 960MHz |
| | 29 | 31 | | dB | RF ON, 1850MHz to 1990MHz |
| | 32 | 34 | | dB | RF ON, 2170MHz to 2500MHz |
| RFC - RF1, RFC - RF2 | 27 | 29 | | dB | RF ON, 600MHz |
| | 25 | 27 | | dB | RF ON, 824MHz to 960MHz |
| | 28 | 30 | | dB | RF ON, 1850MHz to 1990MHz |
| | 31 | 33 | | dB | RF ON, 2170MHz to 2500MHz |
| RF Port Return Loss | | | | | |
| VSWR | | | 1.5:1 | | |
| 880MHz Harmonics | | | | | |
| Second Harmonic | 70 | 91 | | dBc | P _{IN} =26dBm; F _O =880MHz |
| Third Harmonic | 70 | 91 | | dBc | P _{IN} =26dBm; F _O =880MHz |
| 1880MHz Harmonics | | | | | |
| Second Harmonic | 70 | 85 | | dBc | P _{IN} =26dBm; F _O =1880MHz |
| Third Harmonic | 70 | 88 | | dBc | P _{IN} =26dBm; F _O =1880MHz |
| 2500MHz Harmonics | | | | | |
| Second Harmonic | 70 | 82 | | dBc | P _{IN} =26dBm; F _O =2500MHz |
| Third Harmonic | 70 | 86 | | dBc | P _{IN} =26dBm; F _O =2500MHz |

| Parameter | Specification | | | Unit | Condition |
|--|---------------|------|------|------|--|
| | Min. | Typ. | Max. | | |
| IIP2 | | | | | |
| RF1, RF2 - ANT Cell | 104 | 111 | | dBm | Tone 1: 836.5MHz @ 16dBm, Tone 2: 1718MHz @ -20dBm, Receive Freq: 881.5MHz |
| RF1, RF2 - ANT AWS | 105 | 111 | | dBm | Tone 1: 1732.5MHz @ 16dBm, Tone 2: 3865MHz @ -20dBm, Receive Freq: 2132.5MHz |
| RF1, RF2 - ANT PCS | 104 | 108 | | dBm | Tone 1: 1880MHz @ 16dBm, Tone 2: 3840MHz @ -20dBm, Receive Freq: 1960MHz |
| IIP3 | | | | | |
| RF1, RF2 - ANT Cell | 65 | 68 | | dBm | Tone 1: 836.5MHz @ 16dBm, Tone 2: 791.5MHz @ -20dBm, Receive Freq: 881.5MHz |
| RF1, RF2 - ANT IMT | 65 | 67 | | dBm | Tone 1: 1950MHz @ 16dBm, Tone 2: 1760MHz @ -20dBm, Receive Freq: 2140MHz |
| Input Power at 0.1dB Compression Point | | | | | |
| | | 32 | | dBm | |
| Switching Speed | | | | | |
| | | | 600 | ns | 50% to 90% RF ON, 50% to 10% RF OFF |
| DC Supply | | | | | |
| VRF1 and VRF2 (H) | 2.85 | 3.0 | 3.30 | V | |
| VRF1 and VRF2 (L) | 0.00 | | 0.40 | V | |
| Control Current | | | 6.00 | uA | |

Control Logic

| | Control Signals | | Signal Paths | |
|----------------|-----------------|------|----------------------|---------|
| | VRF1 | VRF2 | RF1-RFC | RF2-RFC |
| Valid States | 1 | 0 | ON | OFF |
| | 0 | 1 | OFF | ON |
| Invalid States | 0 | 0 | Indeterminate State* | |
| | 1 | 1 | Indeterminate State* | |

0: Logic level low, 0V~0.4V

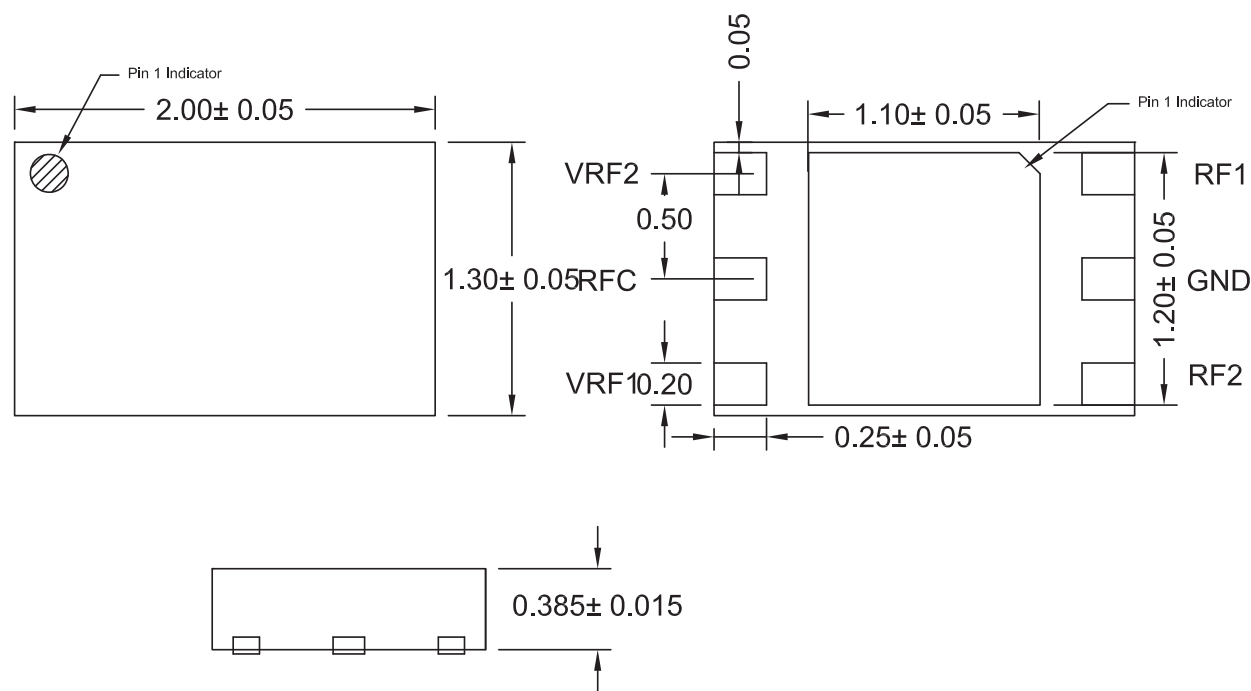
1: Logic level high, 2.85V~3.3V

Note: In indeterminate states, both signal paths are ON with degraded performance.

For low power applications, RF1128 is operable at 1.8V control voltage with no significant change to the Insertion Loss, Return Loss, and Isolation performance.

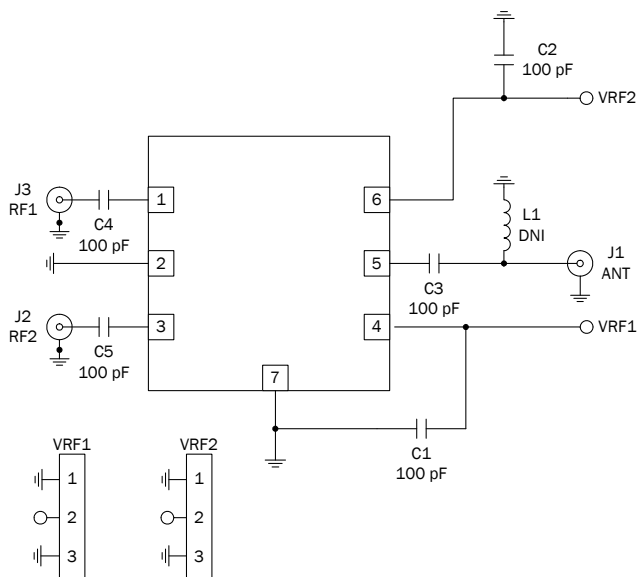
| Pin | Function | Description |
|----------|----------|-------------|
| 1 | RF1 | RF Port 1. |
| 2 | GND | Ground. |
| 3 | RF2 | RF Port 2. |
| 4 | VRF1 | Control 1. |
| 5 | RFC | Antenna. |
| 6 | VRF2 | Control 2. |
| Pkg Base | GND | Ground. |

Package Drawing

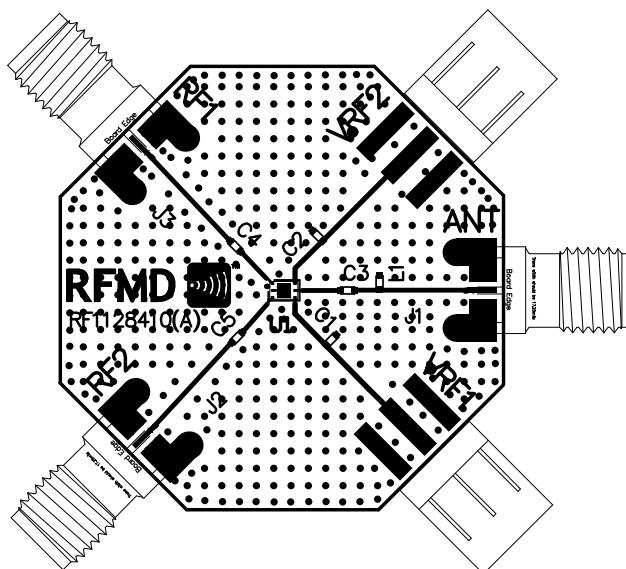


1) PIN 1 INDICATOR SHADED AREA
Notes:

Evaluation Board Schematic



Evaluation Board Layout



Typical Performance Data on Evaluation Board

Note: Fixture losses have been de-embedded (Temp=25 °C, VRF1=VRF2=High=3V, VRF1=VRF2=Low=0V)

